

# 15A, 35V - 150V Dual Common Cathode Schottky Rectifiers

#### FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

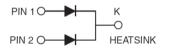
#### **MECHANICAL DATA**

Case: TO-263AB (D<sup>2</sup>PAK)

Molding compound, UL flammability classification rating 94V-0 Moisture sensitivity level: level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test **Polarity:** As marked **Weight:** 1.37 g (approximately)



TO-263AB (D<sup>2</sup>PAK)







MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)									
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1535	1545	1550	1560	1590	15100	15150	Unit
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50	60	90	100	150	V
Maximum RMS voltage	V <sub>RMS</sub>	24	31	35	42	63	70	105	V
Maximum DC blocking voltage	V <sub>DC</sub>	35	45	50	60	90	100	150	V
Maximum average forward rectified current	I <sub>F(AV)</sub>				15				А
Peak repetitive forward current (Rated V <sub>R</sub> , Square wave, 20KHz)	I <sub>FRM</sub>	15				А			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150				А			
Peak repetitive reverse surge current (Note 1)	I <sub>RRM</sub>	1 0.5				А			
Maximum instantaneous forward voltage (Note 2) I <sub>F</sub> = 7.5 A, T <sub>J</sub> =25°C			-	0.	75	0.	92	0.95	
I <sub>F</sub> = 7.5 A, T <sub>J</sub> =125°C	V <sub>F</sub>	0.57		0.	0.65 0 -		82	0.92	0.92 V
I <sub>F</sub> = 15 A, T <sub>J</sub> =25°C		0.	0.84 0.72				-	-	
I <sub>F</sub> = 15 A, T <sub>J</sub> =125°C		0.			-	-		-	
T <sub>J</sub> =25°C		0.1							
Maximum reverse current @ rated $V_R$ $T_J=125^{\circ}C$	I <sub>R</sub>	1	5	1	0		5	m	mA
Voltage rate of change (Rated V <sub>R</sub> )	dV/dt	10000				V/µs			
Typical thermal resistance	R <sub>θJC</sub> R <sub>θJA</sub>	2 50				°C/W			
Operating junction temperature range	TJ	- 55 to +150			°C				
Storage temperature range	T <sub>STG</sub>	- 55 to +150				°C			
Note 1: tp = 2.0 $\mu$ s 1.0KHz									

Note 1: tp = 2.0 µs, 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle



## **MBRS1535CT - MBRS15150CT**

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#### ORDERING INFORMATION

PART NO.	PART NO.	PACKING CODE	PACKING CODE	PACKAGE	PACKING
	SUFFIX		SUFFIX <sup>(*)</sup>		
MBRS15xxCT	Ц	RN	G	D <sup>2</sup> PAK	800 / 13" Paper reel
(Note 1)		MN	9	DPAK	800 / 13" Plastic reel

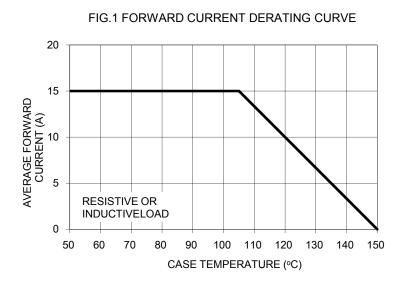
Note 1: "xx" defines voltage from 35V (MBRS1535CT) to 150V (MBRS15150CT)

\*: Optional available

EXAMPLE						
PREFERRED P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
MBRS1560CTHRNG	MBRS1560CT	Н	RN	G	AEC-Q101 qualified Green compound	

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub>=25°C unless otherwise noted)





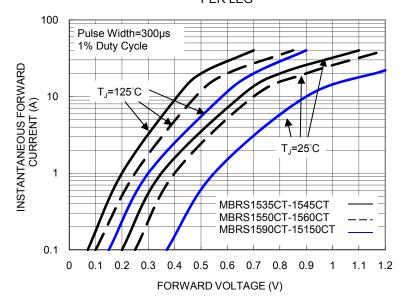


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

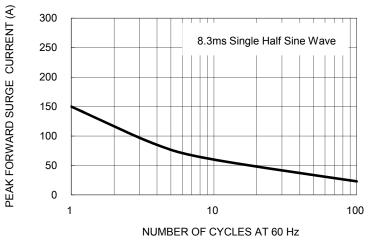
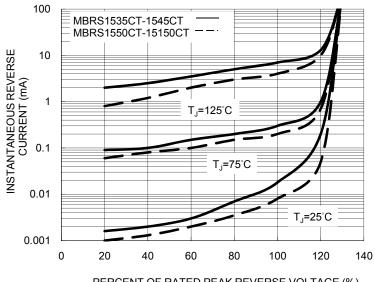
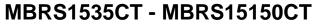


FIG. 4 TYPICAL REVERSE CHARACTERISTICS PER LEG

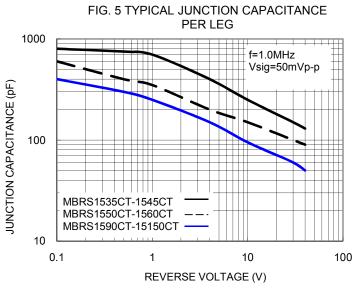


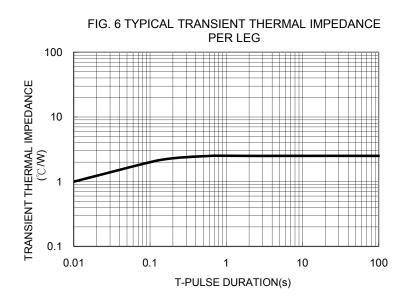
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

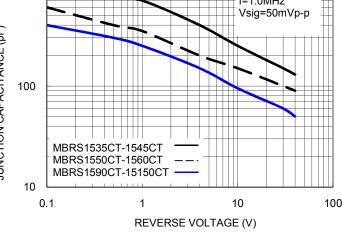


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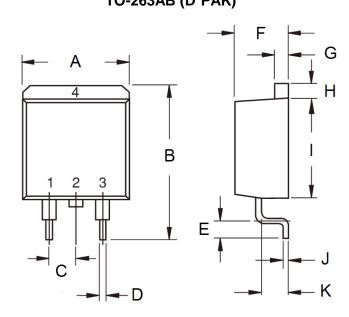




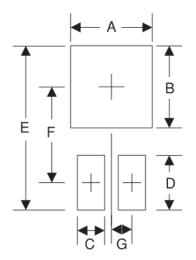


Unit (mm) Unit (inch) DIM. Min Max Min Max 10.5 0.413 А -\_ В 14.60 15.88 0.575 0.625 С 2.41 2.67 0.095 0.105 0.037 D 0.68 0.94 0.027 Е 2.29 2.79 0.090 0.110 F 4.44 4.70 0.175 0.185 G 1.14 1.40 0.045 0.055 Н 1.14 1.40 0.045 0.055 8.25 9.25 0.325 0.364 I J 0.36 0.53 0.014 0.021 Κ 2.03 2.79 0.080 0.110

## PACKAGE OUTLINE DIMENSIONS TO-263AB (D<sup>2</sup>PAK)



### SUGGESTED PAD LAYOUT



P/N

YWW

G

F

Symbol	Unit (mm)	Unit (inch)
A	10.8	0.425
В	8.3	0.327
С	1.1	0.043
D	3.5	0.138
E	16.9	0.665
F	9.5	0.374
G	2.5	0.098

#### **MARKING DIAGRAM**



- = Specific Device Code
- = Green Compound
- = Date Code
- = Factory Code

Document Number: DS\_D1309060



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